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Ultrafast non-local control of spontaneous emission

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The radiative interaction of solid-state emitters with cavity fields is the basis of semiconductor microcavity lasers and cavity quantum electrodynamics (CQED) systems1. Its control in real time would open new avenues for the generation of non-classical light states, the control of entanglement and the modulation of lasers. However, unlike atomic CQED or circuit quantum electrodynamics2–4, the real-time control of radiative processes has not yet been achieved in semiconductors because of the ultrafast timescales involved. Here we propose an ultrafast non-local moulding of the vacuum field in a coupled-cavity system as an approach to the control of radiative processes and demonstrate the dynamic control of the spontaneous emission (SE) of quantum dots (QDs) in a photonic crystal (PhC) cavity on a ~200 ps timescale, much faster than their natural SE lifetimes.

When a two-level emitter in the excited state interacts with the vacuum field of a cavity mode, the evolution of the system is determined by the interplay of the coupling rate $g$, interaction time $T$ and cavity-loss rate $κ$. The control of one or more of these parameters in real time allows optimizing the interaction for the desired application, resulting, for example, in entangled emitter–photon states5, or in single-photon states with an optimized waveform for quantum networking applications5. In atomic CQED systems, the control of the radiative interaction is realized at microwave frequencies by varying the interaction time $T$ in the range of tens of microseconds6, and at optical frequencies by adiabatic passage techniques3–5, which effectively allow the shaping of the coupling rate $g$ on timescales of 100 ns. In superconducting circuit quantum electrodynamics, the cavity-loss rate $κ$ has been changed on a timescale of 100 ns by the electrical control of circuit elements6. However, in semiconductor systems based, for example, on QDs in PhC cavities, these approaches are difficult to implement because of the different energy-level structures and the faster cavity loss and emitter decoherence rate (typically subnanoseconds). The ideal control method for semiconductor nanocavities would allow the ultrafast manipulation of the coupling rate $g$ and/or the cavity-loss rate $κ$, without directly affecting the population and the phase of the emitter. Although various methods for the control of semiconductor CQED systems have been demonstrated, for example by tuning the emitter or cavity frequency using electric field7, strain8 or nanomechanical deformation9,10, none of these has been shown to provide the control of radiative processes on the required subnanosecond timescales. The fast wavelength-detuning techniques theoretically proposed in Johnson et al.11 and Thyregod et al.12 are extremely challenging to implement without directly perturbing the emitter’s evolution, and are intrinsically associated with a wavelength chirp. Here we propose an approach that enables the non-local and ultrafast control of the coupling rate and/or the cavity-loss rate in a solid-state system. We show its implementation in semiconductor QDs weakly coupled to a PhC coupled-cavity system, which demonstrates, for the first time, the ultrafast control of SE dynamics at optical frequencies with a temporal resolution of about 200 ps, which can be reduced further to the few picoseconds range.

Our approach is based on ultrafast moulding of the vacuum field, and thereby the coupling rate and cavity loss, seen by a dipole emitter sitting in a ‘target’ cavity, by changing the resonant wavelength of an adjacent Fabry–Pérot (FP) cavity coupled to the target cavity through a semitransparent mirror (Fig. 1a). When the two cavities are out of resonance, the modes of the system are approximated well by the modes of uncoupled cavities, where, by design, the periodic FP modes have a lower quality factor (Q factor) compared with the mode of the target cavity. A change in the refractive index of the FP cavity produces a spectral shift of the FP modes and brings one of them into resonance with the

![Figure 1](image)

**Figure 1** | Scheme of the non-local control of the emitter–cavity interaction. a, Two cavities with different Q factors and mode volumes are coupled through a semi-transparent mirror. b, Bringing one of the FP cavity modes into the resonance of the target cavity mode produces a redistribution of the mode field and a change of Q factor. c, A schematic image of coupled PhC cavities. The probe laser beam is located at the target cavity to generate the µPL signal and the control laser beam is focused on the FP cavity, at 30 µm distance from the target cavity.
target cavity mode (Fig. 1b). This causes a redistribution of the vacuum field seen by the emitter, with a corresponding increase in the effective mode volume and reduction of the Q factor, and thereby changes the emitter-field coupling rate and the loss rate. If the change of the FP spectrum is produced by an ultrafast laser pulse from the photoexcitation of free carriers, the vacuum field responds within a timescale set by the target–FP coupling rate (typically picoseconds) and the emitter experiences a dynamic modulation of the local density of states (LDOS) during its interaction with the cavity. As the free carriers are injected distant from the target cavity (that is, the control is 'non-local'), they do not directly perturb the population and phase coherence of the emitter. A simple analysis based on coupled-mode theory (see Methods and Supplementary Methods) shows that the emitter interacts with the coupled mode with a rate $g_1 = a g$, where $\alpha$ is the target-cavity component of the electric field of the coupled mode, and $g$ is the interaction rate between the emitter and the uncoupled target cavity. Although this g modulation is generally applicable to any radiative interaction, we focus here on the modulation of the SE rate of emitters weakly coupled to a cavity to give a first experimental demonstration of the concept. The SE rate $\gamma_1$ into one of the coupled modes, normalized by that in the uncoupled target cavity $\gamma_t$, is given by:

$$\frac{\gamma_1}{\gamma_t} \approx \frac{|g_1|^2 x_1}{g x_1} = |\alpha|^2 \frac{Q_1}{Q_t}$$

where $Q_1(x_1)$ and $Q_t(x_t)$ are the Q factors (loss rates) of the coupled mode and uncoupled target cavity, respectively. The SE rate is affected both by the change in the coupling rate $g$ (term $|\alpha|^2$) and loss rate $x_1$, which are controlled by the target-FP detuning. Also, a pure g modulation is possible by choosing the Q factor of the FP cavity equal to that of the target cavity.

We implemented this concept using PhC cavities and QDs as emitters. Coupled PhC cavities were investigated previously as examples of photonic molecules\textsuperscript{15–17}, for Q-factor tuning\textsuperscript{13,14,18} and coupled CQED\textsuperscript{19}. Two double-heterostructure cavities\textsuperscript{20} are defined by slightly modifying the lattice constant along a W1 PhC waveguide from $d_0$ to $d_1 = 1.03 \times d_0$ (Fig. 1c). In the first series of experiments, the change in the SE rate of QDs in the target cavity was characterized in quasi-static conditions by thermo-optic tuning of the FP cavity. The FP modes shift to longer wavelengths because of heating when the excitation power increases\textsuperscript{21}, which changes the detuning between two cavities (Fig. 2a). When the central FP mode anticrosses the target cavity mode, a decrease in emission intensity is observed and the Q factor decreases by a maximum factor of 2.0 (Fig. 2a–c). Depending on the detuning, the cavity wavelength and the Q factor can be fitted well by the coupled-mode theory (Fig. 2b,c). The microphotoluminescence (µPL) decay times strongly depend on the detuning (Fig. 2c,d) and are reproduced well by the Master equation model, taking into account the homogeneous broadening at the measurement temperature of 77 K, estimated as 250 µeV (see the Supplementary Information). After deducting the measured effect of emission into the leaky modes of the PhC, a change in the SE rate in the cavity mode by a factor of 2.7 is derived, which is attributed partly to the relative change in the effective Q (by a factor of ~1.34, see the Supplementary Information) and partly to the redistribution of the vacuum field term $|\alpha|^2$ (by a factor of ~2).

In a second set of experiments, the dynamic control of SE was achieved by replacing the thermo-optic tuning with free-carrier injection. In this case, a pulsed laser injects free carriers into the FP cavity. When the initial detuning between the target and FP
cavity is adjusted to 0 nm, two coupled modes are observed at 1,552.0 and 1,552.4 nm. The laser pulse produces a blue shift of the FP mode, which brings it out of resonance with the target cavity, and the SE rate from QDs in the target cavity is enhanced because of the increase in the Q factor and the increased localization of the vacuum field (Fig. 3a–c). This gives rise to a peak at time zero in the three-dimensional map, which lasts until the FP mode relaxes to the initial wavelength through diffusion and the recombination of free carriers. The duration of this pulse of SE (232 ps at full-width half-maximum (FWHM)) is related to the free-carrier lifetime in the FP cavity, and not to the emitter’s lifetime—this shows the possibility of modulating SE at frequencies of several gigahertz, well above the bandwidth limitation related to the lifetime. This dynamic process is simulated by a Master equation model (see the Supplementary Information), which includes the effect of pumping by several QDs via their homogeneous broadening and reproduces the PL temporal dependence very well (Fig. 3c). The observed modulation depth at the peak, \( I_{\text{max}}/I_0 = 3.3 \), results from the combined effect of the LDOS enhancement, the increase of photon population caused by the Q change and the change in the collection efficiency as a result of the redistribution of the vacuum field.

For the opposite situation of non-zero detuning, the FP and target cavity modes can be transiently brought into resonance (Fig. 3d–f). This produces a sharp dip (246 ps FWHM) in the SE intensity because of the LDOS reduction caused by the vacuum field delocalization and Q-factor decrease, which confirms that the peak in Fig. 3a is not a result of the additional PL produced by the injected carriers. For this case, the measured peak modulation depth is \( I_{\text{f}}/I_{\text{max}} = 2.0 \). Here the modulation occurs over the entire mode spectrum, and clearly differs from the static modulation of the SE rate using PhC cavities\(^{22}\) and the dynamic modulation, which may, in principle, be obtained by changing the emitter–cavity detuning with ultrafast control of the cavity wavelength\(^{11,12,23}\) or by Stark tuning of the exciton energy\(^{9}\). Indeed, our method directly changes the SE rate by controlling the interaction term \( g \) and loss rate \( \kappa \). This allows the chirp of the emitted photons to be minimized. This chirp reduces the coupling efficiency to another cavity and is therefore detrimental to application in quantum-information processing\(^{24}\).

To demonstrate further the flexibility of our approach, we show the control of the temporal SE decay profile of the emitters in the target cavity. In this case, both the target and the FP cavity are pumped by the same pulsed laser, with variable delay. The excitation power at the target cavity produces an initial blue shift in the target cavity mode (as seen in the inset of Fig. 4a) caused by free-carrier injection. To avoid the effect of this blue shift we choose delays such that the target cavity wavelength is stabilized. When the initial detuning is zero and the pulse exciting at the FP cavity is delayed by 2.0 ns, a spike is observed in the PL signal collected from the target cavity when the FP mode is brought out of resonance. The timing of the spike can be controlled by the delay, as shown in Fig. 4a for delays of 1.5, 2.0 and 2.5 ns. For the opposite situation in which the static detuning between coupled modes is set to 0.6 nm, the FP mode is transiently brought into resonance so that the expected dip appears (Fig. 4b).

In our demonstration, the temporal resolution is determined by the free-carrier lifetime, which potentially can be reduced down to a few picoseconds by applying an electric field in the control cavity\(^{25}\). This would allow shaping of the control-cavity frequency and thereby the LDOS at the target cavity on picosecond timescales by the simple control of the pump–pulse temporal profile.

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**Figure 3 | Dynamic control of SE at the target cavity.**

**a** A time-resolved PL map, for an initial detuning of 0 nm, made by measuring the decay curves at different wavelengths. The target cavity is excited with a CW laser source when the pulse excitation at the FP cavity brings the FP mode out of resonance. The curve at the backplane is the measured time-resolved PL trace at a wavelength of 1,552.2 nm. **b** Top view of the map in a, c. The simulation results compared to b. The uncoupled wavelengths of the target and FP modes are shown by the white dotted curves. **d–f**. The same as a–c for an initial detuning of 0.6 nm. The curve at the backplane is the measured time-resolved PL trace at a wavelength of 1,551.2 nm.
The measurement was performed at 77 K using a confocal setup.

Methods

Coupled-mode theory. The system of three coupled oscillators (the emitter, the target and FP cavities) can be described by a non-Hermitian Hamiltonian:

\[
H = \begin{bmatrix}
\omega_1 & \beta g & \kappa_1 \\
\beta g & \omega_2 - \kappa_2 & \kappa_2 \\
0 & \kappa_2 & \omega_2 - \kappa_2
\end{bmatrix}
\]

where \(\omega_1\), \(\omega_2\) and \(\omega_\text{FP}\) are the angular frequencies of the emitter, the uncoupled target and the FP cavity modes, respectively, and \(\kappa_1\) and \(\kappa_2\) are the corresponding loss rates. We assume that the emitter couples only to the target cavity with an interaction strength \(g\), where we fix the interaction to the weak coupling regime \(g \ll \kappa_1, \kappa_2\). The coupling rate between the two cavities is \(\kappa\). By diagonalizing the \(2 \times 2\) submatrix of the cavities, the normalized mode functions \(E_{\text{cav}}(r)\) of the coupled modes are calculated on the basis of the isolated cavity modes \(E_\text{FP}(r)\) and \(E_\text{cav}(r)\).

which shows that the SE is affected both by the change in the coupling rate \(g\) (term \(\kappa\)) and loss rate \(\kappa\). This simple model applies to a single, spectrally narrow emitter. As our experiments involve an ensemble of QDs with non-negligible homogeneous broadening, the Master equation, with the addition of the emitter’s decoherence and incoherent pumping, has been used to reproduce the data in Figs 2 and 3. More details are provided in the Supplementary Information.

Sample preparation. The sample was grown on an InP(100) substrate by metal-organic vapour phase epitaxy. The structure contains an InP buffer layer of thickness 100 nm, followed by a 110 nm lattice-matched InGaAsP layer with a bandgap at 0.992 eV (Q1.25), a GaAs interlayer 1.2 monolayers thick, a single layer of InAs QDs, a 110 nm InGaAsP layer and a 50 nm InP capping layer. The QDs have an areal density of \(2 \times 10^{10}\) cm\(^{-2}\) and provide a 100 nm broad luminescence peak around 1.550 nm (Ref. 28), which feeds the cavity mode. The PhC cavities were fabricated with a standard process of electron-beam lithography and inductively coupled plasma using a C\(_3\)H\(_4\)/Ar/H\(_2\) mixture. The selective wet etching of the PhC sacrificial layer was carried out in a HCl/H\(_2\)O solution at 2 °C. The cavity constant of PhC is chosen to be \(\kappa_\text{cavity} = 480\) ns with a filling factor of 0.30 to achieve a cavity mode around 1.550 nm at 77 K. The target and FP cavity consist of two and 80 periods of modulated lattice constant \(\alpha_1 = 1.03 \times \alpha_0\), respectively. The barrier between two cavities contains four periods of the original lattice constant.

Experimental set-up. The measurement was performed at 77 K using a confocal microscopy set-up in which two laser beams are focused at different positions with a separation of 30 µm, as indicated in the sketch in Fig. 1c. The temperature was chosen to facilitate the thermal tuning of the cavities. The µPL signal from the target cavity was collected by the objective and measured with a spectrometer. The experiments on thermo-optic tuning (Fig. 2) were performed by exciting the target cavity with a pulsed laser at 1.064 nm, pulse width of 6 ps and energy of 2 µl cm\(^{-2}\) per pulse, with the FP cavity heated by a continuous wave (CW) beam at 780 nm. Decay curves at different detunings were measured by time-correlated single-photon counting (TCSPC) using a superconducting single-photon detector. In the ultrafast tuning experiments (Fig. 3) the target cavity was pumped with the CW beam at 780 nm as the FP cavity was excited with a pulsed laser at 1.064 nm, pulse width of 6 ps and energy of 2 µJ cm\(^{-2}\) per pulse, with the FP cavity heated by a continuous wave (CW) beam at 780 nm. Decay curves at different detunings were measured by time-correlated single-photon counting (TCSPC) using a superconducting single-photon detector.

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References

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Author contributions

A.F. proposed the experiment and led the project. C.Y.J., M.Y.S. and L.M. performed the optical simulations. P.I.V. grew the sample. C.Y.J. designed and fabricated the devices. C.Y.J., M.Y.S. and T.B.H. performed the measurements. R.J. developed the theory. C.Y.J., R.J., A.F. and L.M. performed the theoretical aspects and to P. M. Koenraad and E. Pelucchi for a critical reading of the manuscript. This research is supported financially by NanoNextNL, a micro and nanotechnology program of the Dutch Ministry of Economic Affairs, Agriculture and Innovation (EL&I) and 130 partners, the Dutch Technology Foundation STW, Applied Science Division of NWO, the Technology Program of the Ministry of Economic Affairs under project No. 10380 and the FOM project No. 09PR2675. One of the authors (A.F.) dedicates this work to the memory of E. Rosencher.

Additional information

Supplementary information is available in the online version of the paper. Reprints and permissions information is available online at www.nature.com/reprints. Correspondence and requests for materials should be addressed to C.Y.J.

Competing financial interests

The authors declare no competing financial interests.